

OCT 01 2003

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Appl. No. : 09/888,494  
Applicant : Han-Chao LAI ET AL  
Field : June 26, 2001  
TC/A.U. : 2814  
Examiner : Long Pham  
Docket No. : 4425-154  
Title : METHOD FOR FORMING A METAL OXIDE  
SEMICONDUCTOR TYPE FIELD EFFECT  
TRANSISTOR

Commissioner for Patent

P. O. Box 1450  
Alexandria VA 22313-1450

**RESPONSE**

Sir:

In response to the Office Action of July 1, 2003, please reconsider the above-identified application as follows:

This present amendment is in response to the Office Action mailed July 01, 2003, Claims 1-8 were rejected under 35 U.S.C. 103(a) as being unpatentable over Gardner et al (U.S., Patent No. 6,130454A) and Hsu et al (U.S. Patent No. 6,221,767B1); Claims 9-18 were rejected under 35 U.S.C. 103(a) as being unpatentable over Gardner